HEWLETT-PACKARD COMPANY Intellectual Property Administration P.O. Box 272400 Fort Collins, Colorado 80527-2400

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IN THE

UNITED STATES PATENT AND TRADEMARK OFFICE

Inventor(s): Randy Hoffman et al. Confirmation No.: 7102

Application No.: 10/763,353 Examiner: MONDT, Johannes P.

Filing Date: January 23, 2004 Group Art Unit: 3663

Title: Semiconductor Device

Mail Stop Appeal Brief - Patents Commissioner For Patents PO Box 1450 Alexandria, VA 22313-1450

TRANSMITTAL OF REPLY BRIEF

Transmitted herewith is the Reply Brief with respect to the Examiner's Answer mailed on _____ May 15, 2009 ____.

This Reply Brief is being filed pursuant to 37 CFR 1.193(b) within two months of the date of the Examiner's Answer.

(Note: Extensions of time are not allowed under 37 CFR 1.136(a))

(Note: Failure to file a Reply Brief will result in dismissal of the Appeal as to the claims made subject to an expressly stated new ground rejection.)

No fee is required for filing of this Reply Brief.

If any fees are required please charge Deposit Account 08-2025.

Respectfully submitted, Randy Hoffman et al.

By: /Steven L. Nichols/

Steven L. Nichols

Attorney/Agent for Applicant(s)

Reg No.: 40,326

Date: July 8, 2009 Telephone: 801-572-8066

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REPLY BRIEF

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Sir:

This is a Reply Brief under Rule 41.41 (37 C.F.R) in response to the Examiner's Answer of May 15, 2009 (the "Examiner's Answer" or the "Answer"). In Section 10, the Answer contains a response to some of the arguments made in Appellant's brief. Appellant now responds to the Examiner's Answer as follows.

Status of Claims

Claims 1-3, 5, 10, 13, 16-18, 20-25, 27-30, 40-47, 49, 51-53, 56-59, 61-63, and 65-67 were cancelled previously without prejudice or disclaimer. Thus, claims 4, 6-9, 11, 12, 14, 15, 19, 26, 31-39, 48, 50, 54, 55, 60, and 64 are pending in the present application and stand finally rejected. Accordingly, Appellant appeals from the final rejection of claims 4, 6-9, 11, 12, 14, 15, 19, 26, 31-39, 48, 50, 54, 55, 60, and 64, which claims are presented in the Appendix to Appellant's Brief.

Grounds of Rejection to be Reviewed on Appeal

The final Office Action raised the following grounds of rejection.

- (1) Claims 4, 6-9, 11, 26, 31-36, 48, 50, 54, 55, and 60 were rejected under 35 U.S.C. §102(e) as allegedly being anticipated by U.S. Patent App. Pub. No. 2004/0127038 to Carcia et al. ("Carcia").
- (2) Claim 19 was rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over the combined teachings of Carcia and U.S. Patent No. 4,521,698 to Taylor ("Taylor").
- (3) Claim 12 was rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over the combined teachings of Carcia and U.S. Patent No. 6,674,495 to Hong et al. ("Hong").
- (4) Claims 14 and 38 were rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over the combined teachings of Carcia and U.S. Patent No. (6,100,558) to Krivokapic et al. ("Krivokapic").
- (5) Claims 15 and 39 were rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over the combined teachings of Carcia, Krivokapic and U.S. Patent App. Pub. No. 2004/0169210 to Hornik et al. ("Hornik").
- (6) Claim 64 was rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over the combined teachings of Carcia and U.S. Patent No. 5,744,864 to Cillessen et al. ("Cillessen") and U.S. Patent No. (6,184,946) to Ando et al. ("Ando").
- (7) Claims 4, 7-9, 12, 19, 26, 32-35, 37, 48, 50, 54, 55, 60 and 64 were rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over Cillessen.
- (8) Claims 6, 11, 31 and 36 were rejected under 35 U.S.C. §103(a) as allegedly being unpatentable over the combined teachings of Cillessen and Carcia.

According, Appellant hereby requests review of each of these grounds of rejection in the present appeal.

Argument

(1) Claims 4, 6-9, 11, 26, 31-36, 48 and 50, 54, 55, 60 are patentable over Carcia.

Independent claims 4, 48, 50 and 60:

For convenience, claim 4 is reproduced again here as representative of these independent claims at issue Claim 4 recites:

A semiconductor device, comprising:

- a source electrode;
- a drain electrode;
- a channel coupled to the source electrode and the drain electrode and comprised of a ternary compound containing zinc, tin and oxygen, where at least a portion of the channel is formed from a zinc-tin oxide compound having the following stoichiometry: Zn_2SnO_4 : and
- a gate electrode configured to permit application of an electric field to the channel.

(Emphasis added)

Independent claims 4, 48, 50, and 60 all recite, *inter alia*, a channel which comprises a zinc-tin oxide. The final Office Action, in a §102 rejection, asserts that Carcia, in paragraph 0010, teaches a channel comprised "ternary compound containing zinc, tin and oxygen." (Action, p. 2). Paragraph 0010 of Carcia is reproduced below, in relevant part.

This invention relates to novel, transparent oxide semiconductor (TOS) thin film transistors (TFT's) and the process for their deposition, where the transparent oxide semiconductor (TOS) is selected from the group consisting of zinc oxide (ZnO), indium oxide (In20 3), tin oxide (Sn02), or cadmium oxide (CdO) semiconductor and combinations thereof.

The Final Action erred in citing paragraph 0010 of Carcia against the present application because the subject matter of paragraph 0010 is not prior art.

The Appellant notes that the present application claims priority to a provisional application, serial number 60/490,239 which was filed on July 25, 2003 (hereafter "Hoffman provisional"). Carcia was filed well after that date on Sept. 24, 2003, but claims priority to an

earlier provisional application, serial number 60/417,767 (hereinafter "Carcia provisional") which was filed Oct. 11, 2002. Consequently, only subject matter within Carcia that was previously disclosed in the Carcia provisional is available as prior art against the present application. As it turns out, this excludes paragraph 0010 of Carcia, on which the final Office Action relies, from being prior art.

The Carcia provisional is directed solely toward zinc oxide as a channel material. The Carcia provisional is absolutely silent with regard to tin, any tin compound, or any combination of zinc oxide with tin. As a result, Carcia is not a prior art for any teaching of "a channel layer formed *from a zinc-tin oxide material*," (emphasis added) as recited in Appellant's claims. For at least this reason, the rejection of Appellant's claims based on Carcia cannot be sustained.

Rebuttal of Examiner's Answer

The Examiner's Answer argues that the Hoffman provisional does not contain the claimed subject matter and therefore does not provide the present application with an effective date which antedates Carcia. This is incorrect. The Hoffman provisional provides ample disclosure of "a channel layer formed from a zinc-tin oxide material." For example, the title of the Hoffman provisional is "Transparent Thin-film Transistor with *Zinc-Tin Oxide Channel Layer*." Additional support for a "channel layer formed form zinc-tin oxide material" is found in the Hoffman provisional, for example, in the Abstract, Summary of the Invention, page 6, and in claim 1.

As discussed above, the Carcia provisional is absolutely silent with regard to tin, any tin compound, or any combination of zinc oxide with tin. Consequently, the *Hoffman* provisional provides the present application with an effective date for this claimed subject

matter which antedates any disclosure of Carcia with respect to the recited "channel layer formed from a zinc-tin oxide material."

Additionally, even if paragraph 0010 of Carcia were prior art against the present application, which it is not, Carcia still does not teach those of skill in the art that zinc-tin oxide is used as channel material. As discussed in the Appellant's Appeal Brief, Carcia never discloses any ternary zinc-tin oxide or any other ternary compound. Second, one of skill in the art would **not** have understood "and combinations thereof" to include ternary zinc-tin oxide. Ternary compounds, particularly amorphous ternary compounds, were generally assumed by those of skill in the art to have poor electron mobility, rendering them unsuitable for transistor channels.

"A claim is anticipated [under 35 U.S.C. § 102] only if each and every element as set forth in the claim is found, either expressly or inherently described, in a single prior art reference." *Verdegaal Bros. v. Union Oil Co. of California*, 2 U.S.P.Q.2d 1051, 1053 (Fed. Cir. 1987). See M.P.E.P. § 2131. As demonstrated here, the cited portions of Carcia are not prior art. Further, Carcia does not teach or suggest all the features of claims 4, 48, 50, and 60.

Additionally, "[t]he prior art reference—in order to anticipate under 35 U.S.C. § 102—must not only disclose all elements of the claim within the four corners of the document, but must also disclose those elements 'arranged as in the claim." *NetMoneyIn v. Verisign*, (Fed. Cir. 2008) (quoting *Connell v. Sears, Roebuck & Co.*, 722 F.2d 1542 (Fed. Cir. 1983)). Carcia clearly fails to teach or suggest all the elements of claims 4, 48, 50 and 60 as arranged in those claims.

. Therefore, for at least the reasons explained here, the rejection based on 35 U.S.C. § 102(b) of claims 4, 48, 50, and 60 and their dependent claims should not be sustained.

(7) Claims 4, 7-9, 12, 19, 26, 32-35, 37, 48, 50, 54, 55, 60 and 64 are patentable over Cillessen.

Claims 4, 7-9, 12, 19, 26, 32-35, 37, 48, 50, 54, 55, 60 and 64 were alternatively rejected under 35 U.S.C. 103(a) as allegedly being unpatentable over Cillessen. As set forth above, independent claims 4, 19, 48, 60, and 64 recite "a zinc-tin oxide compound having the following stoichiometry: Zn₂SnO₄" and independent claim 50 recites "a ternary compound containing zinc, tin, and oxygen having the stoichiometry: (ZnO)_j(SnO₂)_{1-j}, where j is between 0.05 and 0.95." Cillessen fails to teach or suggest this subject matter.

The Examiner repeatedly refers to the following portion of Cillessen and asserts that this disclosure puts one of skill in the art in possession of the claimed subject matter.

It is also possible to use other covalent oxides of a non-transition metal provided with dopant atoms for the semiconductor material of the channel region 4. Oxides of these metals and mixtures of oxides of these metals have a mobility greater 10 cm²/V*s and a bandgap greater than 2.5 eV. For example, Ga₂O₃, Bi₂O₃, SnO₂, ZnO, Sb₂O₃, PbO, GeO₂, or In₂O₂, mixtures of these oxides or compounds formed from these oxides such as GaInO₂, ZnGa₂O₄ or CdGa₂O₄ may be used.

(Cillessen, col. 5, lines 34-43)

Thus, Cillessen provides a list of eight different binary compounds and states that "mixtures of these oxides or compounds formed from these oxides" may be used. (Cillessen, col. 5, lines 34-43). While zinc oxide and tin oxide are included amongst the list of eight different compounds, the number of possible combinations that could be created from the disclosed list is extremely large.

In the Appellant's Appeal Brief, the Appellant included several illustrative lists of possible "*mixtures* of these oxides or *compounds* formed from these oxides." (Appeal Brief, p. 24-30). In total, the Appellant listed approximately 486 possible compounds which are illustrative of "*mixtures* of these oxides or *compounds* formed from these oxides."

Rebuttal of Examiner's Answer

The Examiner's Answer states that the listing given by the Appellant in the Appeal Brief "misrepresents" and "overestimate(s)" of the number of combinations of "combined compounds." The Appellant disagrees with the Examiner for a number of reasons discussed below.

As stated in the Appeal brief, the illustrative lists are a *serious underestimate* of the possible "*mixtures* of these oxides or *compounds* formed from these oxides" taught by Cillessen. A chemical mixture is "an aggregate of two or more substances that are not chemically united and that exist in no fixed proportion to each other." (*Dictionary.com Unabridged (v 1.1)*. Random House, Inc. http://dictionary.reference.com/browse/Mixture (accessed: June 19, 2009). Mixtures may be either homogeneous or heterogeneous.

The Examiner conveniently ignores that Cillessen teaches *mixtures* of the oxides and focuses on arguing that there are a limited number of "combined compounds" which are operable due to "valence" conditions. (Examiner's Reply, p. 26). Ignoring that Cillessen teaches *mixtures* of the oxides is a misrepresentation of the art. One of ordinary skill in the art who read Cillessen would not know that the operable substance claimed by Appellant is a compound. Rather, the person of ordinary skill in the art would be faced with *all possible mixtures* and *all possible compounds* taught by Cillessen. To limit Cillessen's teaching to compounds, excluding mixtures, in an attempt to reach Appellant's claimed subject matter is clearly an exercise of impermissible hindsight on the part of the Examiner.

Mixtures are not limited by "valence" conditions and can be formed of any number of the eight disclosed oxides mixed in any proportion. The illustrative lists in the Appeal Brief include combinations containing only up to four oxides. Cillessen makes no such limitation.

Consequently a complete listing of combinations taught by Cillessen would include additional combinations of five, six, seven, and eight oxides. Further, a complete list would necessarily include all possible proportions of any of the eight oxides included in each mixture.

Further, a mixture which is heterogeneous does not have a uniform composition throughout the mixture. This gives rise to a number of structural, phase segregation, or other variations which further increases the number of possibilities faced by a person of ordinary skill in the art who is relying on the teachings of Cillessen.

The fact that there are a number of combinations which do not form chemical bonds due to molecular bonding constraints (as pointed out by the Examiner's Reply, p. 16) only complicates the inquiry by including inoperable embodiments. Further, a large number of the compounds, although chemically viable, may not have the performance characteristics desired to operate as a thin film transistor channel. This low likelihood of success, combined with the overwhelming number of "mixtures of these oxides" and "compounds formed from these oxides" does not teach or suggest to one of skill in the art that Zn₂SnO₄ should be selected and is suitable for a channel in a transparent thin film transistor.

Clearly, as demonstrated above, the cited prior art did not enable the claimed invention or place those skilled in the art in possession of the invention, unless impermissible hindsight is invoked. Moreover, as mentioned above, the claimed invention is contrary to the generally accepted wisdom in the art. Ternary compounds, particularly amorphous ternary compounds, were generally understood to have poor electron mobility, rendering them unsuitable for transistor channels. (Appellant's specification, p. 2).

Under the analysis required by *Graham v. John Deere*, 383 U.S. 1 (1966) to support a rejection under § 103, the scope and content of the prior art must first be determined, followed by an assessment of the differences between the prior art and the claim at issue in

view of the ordinary skill in the art. In the present case, the scope and content of the prior

art, as evidenced by Cillessen, does not teach or suggest to one of ordinary skill in the art "a

zinc-tin oxide compound having the following stoichiometry: Zn₂SnO₄" or a "ternary

compound containing zinc, tin, and oxygen stoichiometry: (ZnO)_i(SnO₂)_{1-i}, where j is

between 0.05 and 0.95."

The differences between the cited prior art and the claimed subject matter are

significant because ternary zinc-tin oxides used as channel layers provide unexpected electron

mobility which results in superior performance as a channel layer in a transparent thin film

transistor. Thus, the claimed subject matter provides features and advantages not known or

available in the cited prior art. Consequently, the cited prior art will not support a rejection of

4, 19, 48, 50, 60, and 64 and their dependent claims under 35 U.S.C. § 103 and Graham.

In view of the foregoing, it is submitted that the final rejection of the pending claims

is improper and should not be sustained. Therefore, a reversal of the Rejection of June 2,

2008 is respectfully requested.

Respectfully submitted,

DATE: July 8, 2009

/Steven L. Nichols/ Steven L. Nichols

Registration No. 40,326

Steven L. Nichols, Esq.

Managing Partner, Utah Office

Rader Fishman & Grauer PLLC

River Park Corporate Center One

10653 S. River Front Parkway, Suite 150

South Jordan, Utah 84095

(801) 572-8066

(801) 572-7666 (fax)

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